



# PBSS4021SP

20 V, 6.3 A PNP/PNP low  $V_{CEsat}$  (BISS) transistor

Rev. 2 — 11 October 2010

Product data sheet

## 1. Product profile

### 1.1 General description

PNP/PNP low  $V_{CEsat}$  Breakthrough In Small Signal (BISS) transistor in a SOT96-1 (SO8) medium power Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

| Type number | Package  |      | NPN/PNP complement | NPN/PNP complement |
|-------------|----------|------|--------------------|--------------------|
|             | Nexperia | Name |                    |                    |
| PBSS4021SP  | SOT96-1  | SO8  | PBSS4021SN         | PBSS4021SPN        |

### 1.2 Features and benefits

- Low collector-emitter saturation voltage  $V_{CEsat}$
- High collector current capability  $I_C$  and  $I_{CM}$
- High collector current gain ( $h_{FE}$ ) at high  $I_C$
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

### 1.3 Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

### 1.4 Quick reference data

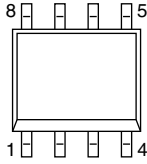
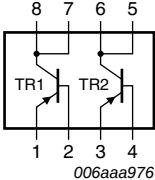
Table 2. Quick reference data

| Symbol      | Parameter                               | Conditions                                       | Min | Typ | Max  | Unit       |
|-------------|-----------------------------------------|--------------------------------------------------|-----|-----|------|------------|
| $V_{CEO}$   | collector-emitter voltage               | open base                                        | -   | -   | -20  | V          |
| $I_C$       | collector current                       |                                                  | -   | -   | -6.3 | A          |
| $I_{CM}$    | peak collector current                  | single pulse;<br>$t_p \leq 1$ ms                 | -   | -   | -15  | A          |
| $R_{CEsat}$ | collector-emitter saturation resistance | $I_C = -5$ A; $I_B = -0.5$ A <a href="#">[1]</a> | -   | 36  | 54   | m $\Omega$ |

[1] Pulse test:  $t_p \leq 300$   $\mu$ s;  $\delta \leq 0.02$ .

## 2. Pinning information

Table 3. Pinning

| Pin | Description   | Simplified outline                                                                  | Graphic symbol                                                                                   |
|-----|---------------|-------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------|
| 1   | emitter TR1   |  | <br>006aaa976 |
| 2   | base TR1      |                                                                                     |                                                                                                  |
| 3   | emitter TR2   |                                                                                     |                                                                                                  |
| 4   | base TR2      |                                                                                     |                                                                                                  |
| 5   | collector TR2 |                                                                                     |                                                                                                  |
| 6   | collector TR2 |                                                                                     |                                                                                                  |
| 7   | collector TR1 |                                                                                     |                                                                                                  |
| 8   | collector TR1 |                                                                                     |                                                                                                  |

## 3. Ordering information

Table 4. Ordering information

| Type number | Package |                                                           |         |
|-------------|---------|-----------------------------------------------------------|---------|
|             | Name    | Description                                               | Version |
| PBSS4021SP  | SO8     | plastic small outline package; 8 leads; body width 3.9 mm | SOT96-1 |

## 4. Marking

Table 5. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PBSS4021SP  | 4021SP       |

## 5. Limiting values

Table 6. Limiting values

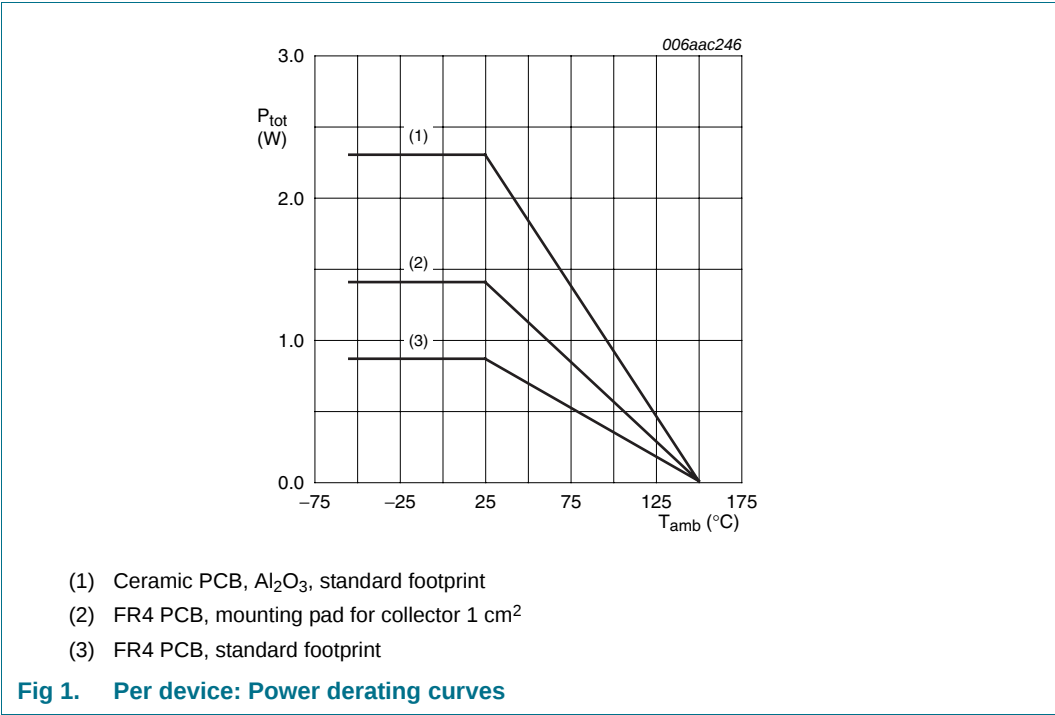
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter                 | Conditions                          | Min   | Max  | Unit |
|------------------|---------------------------|-------------------------------------|-------|------|------|
| Per transistor   |                           |                                     |       |      |      |
| V <sub>CBO</sub> | collector-base voltage    | open emitter                        | -     | −20  | V    |
| V <sub>CEO</sub> | collector-emitter voltage | open base                           | -     | −20  | V    |
| V <sub>EBO</sub> | emitter-base voltage      | open collector                      | -     | −5   | V    |
| I <sub>C</sub>   | collector current         |                                     | -     | −6.3 | A    |
| I <sub>CM</sub>  | peak collector current    | single pulse; t <sub>p</sub> ≤ 1 ms | -     | −15  | A    |
| I <sub>B</sub>   | base current              |                                     | -     | −1   | A    |
| P <sub>tot</sub> | total power dissipation   | T <sub>amb</sub> ≤ 25 °C            | [1] - | 0.73 | W    |
|                  |                           |                                     | [2] - | 1    | W    |
|                  |                           |                                     | [3] - | 1.7  | W    |

Table 6. Limiting values ...continued  
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions               | Min   | Max  | Unit |
|------------------|-------------------------|--------------------------|-------|------|------|
| Per device       |                         |                          |       |      |      |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> ≤ 25 °C | [1] - | 0.86 | W    |
|                  |                         |                          | [2] - | 1.4  | W    |
|                  |                         |                          | [3] - | 2.3  | W    |
| T <sub>j</sub>   | junction temperature    |                          | -     | 150  | °C   |
| T <sub>amb</sub> | ambient temperature     |                          | -55   | +150 | °C   |
| T <sub>stg</sub> | storage temperature     |                          | -65   | +150 | °C   |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.  
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.  
[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol         | Parameter                                        | Conditions  | Min   | Typ | Max | Unit |
|----------------|--------------------------------------------------|-------------|-------|-----|-----|------|
| Per transistor |                                                  |             |       |     |     |      |
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | in free air | [1] - | -   | 170 | K/W  |
|                |                                                  |             | [2] - | -   | 125 | K/W  |
|                |                                                  |             | [3] - | -   | 75  | K/W  |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |             | -     | -   | 40  | K/W  |
| Per device     |                                                  |             |       |     |     |      |
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | in free air | [1] - | -   | 145 | K/W  |
|                |                                                  |             | [2] - | -   | 90  | K/W  |
|                |                                                  |             | [3] - | -   | 55  | K/W  |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.  
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.  
[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

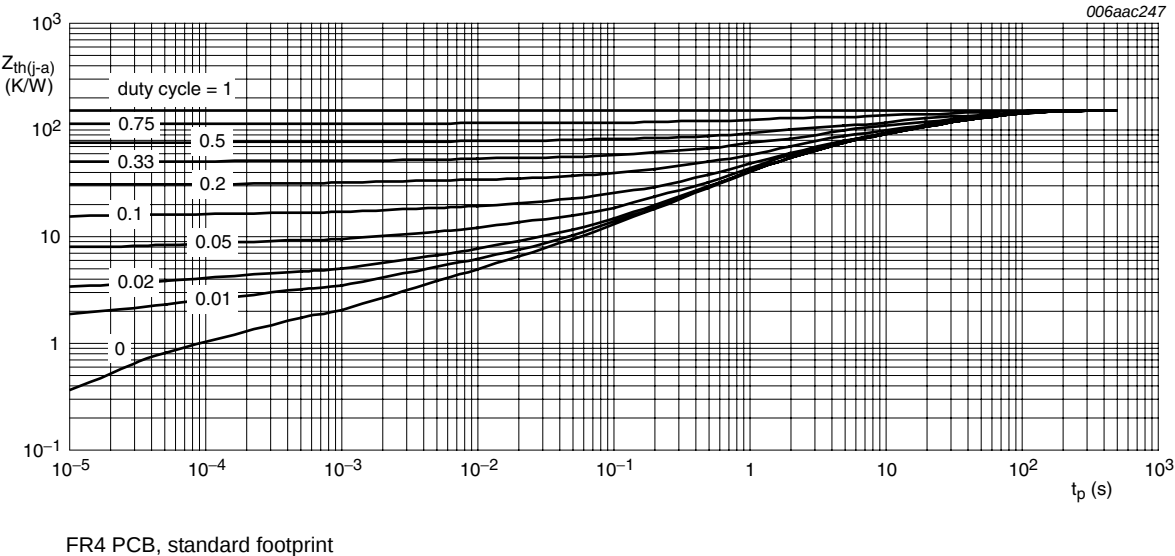
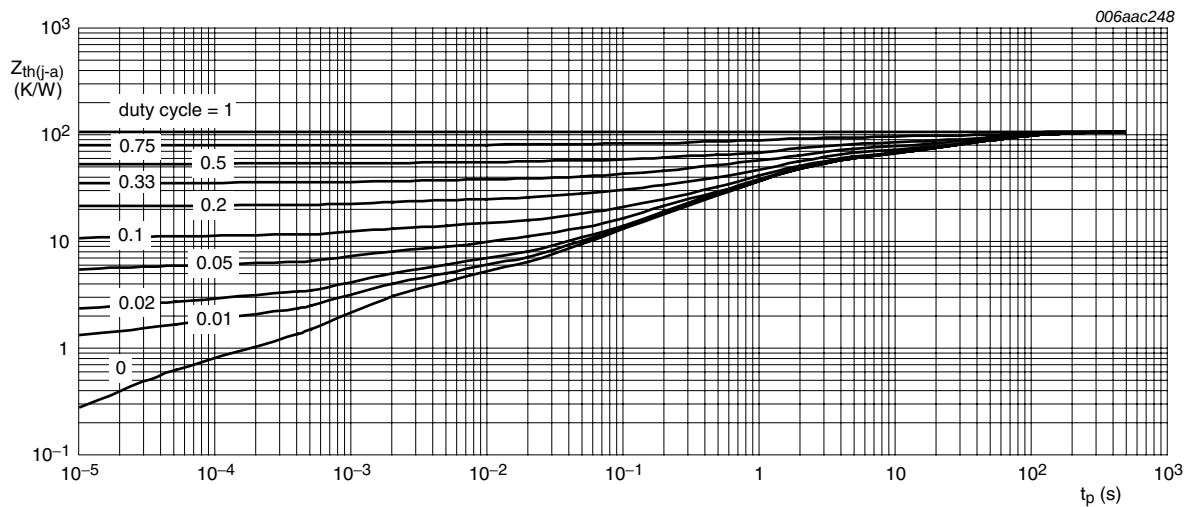
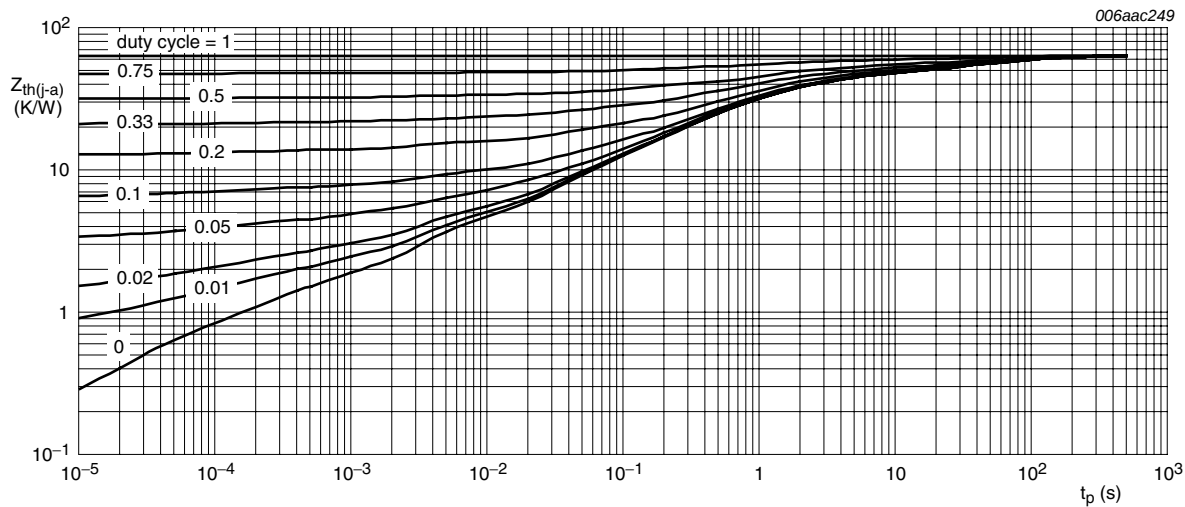


Fig 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>

**Fig 3.** Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

**Fig 4.** Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

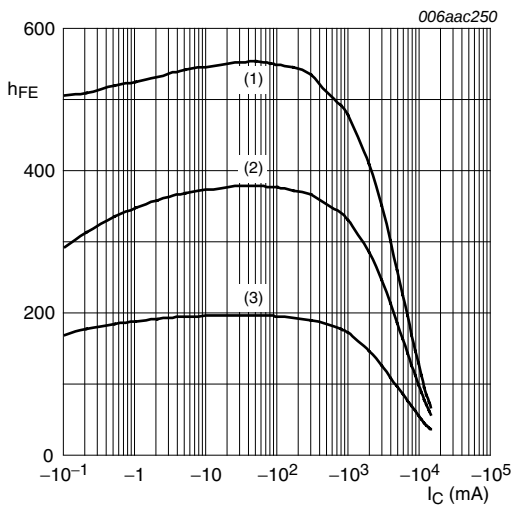
## 7. Characteristics

**Table 8. Characteristics**

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

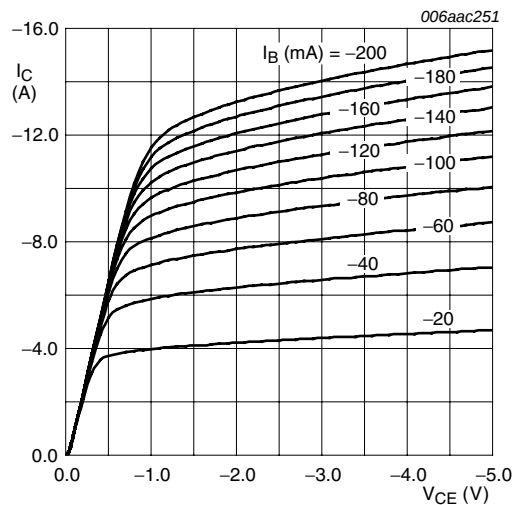
| Symbol             | Parameter                                         | Conditions                                                                   | Min                   | Typ   | Max   | Unit |
|--------------------|---------------------------------------------------|------------------------------------------------------------------------------|-----------------------|-------|-------|------|
| Per transistor     |                                                   |                                                                              |                       |       |       |      |
| I <sub>CBO</sub>   | collector-base cut-off current                    | V <sub>CB</sub> = −20 V; I <sub>E</sub> = 0 A                                | -                     | -     | −100  | nA   |
|                    |                                                   | V <sub>CB</sub> = −20 V; I <sub>E</sub> = 0 A;<br>T <sub>j</sub> = 150 °C    | -                     | -     | −50   | μA   |
| I <sub>CES</sub>   | collector-emitter cut-off current                 | V <sub>CE</sub> = −16 V; V <sub>BE</sub> = 0 V                               | -                     | -     | −100  | nA   |
| I <sub>EBO</sub>   | emitter-base cut-off current                      | V <sub>EB</sub> = −5 V; I <sub>C</sub> = 0 A                                 | -                     | -     | −100  | nA   |
| h <sub>FE</sub>    | DC current gain                                   | V <sub>CE</sub> = −2 V                                                       | <a href="#">[1]</a>   |       |       |      |
|                    |                                                   | I <sub>C</sub> = −500 mA                                                     | 250                   | 400   | -     |      |
|                    |                                                   | I <sub>C</sub> = −1 A                                                        | 250                   | 400   | -     |      |
|                    |                                                   | I <sub>C</sub> = −2 A                                                        | 200                   | 350   | -     |      |
|                    |                                                   | I <sub>C</sub> = −4 A                                                        | 150                   | 300   | -     |      |
|                    |                                                   | I <sub>C</sub> = −7 A                                                        | 80                    | 200   | -     |      |
| V <sub>CEsat</sub> | collector-emitter saturation voltage              | <a href="#">[1]</a>                                                          |                       |       |       |      |
|                    |                                                   | I <sub>C</sub> = −1 A; I <sub>B</sub> = −50 mA                               | -                     | −45   | −68   | mV   |
|                    |                                                   | I <sub>C</sub> = −1 A; I <sub>B</sub> = −10 mA                               | -                     | −70   | −115  | mV   |
|                    |                                                   | I <sub>C</sub> = −2 A; I <sub>B</sub> = −40 mA                               | -                     | −100  | −150  | mV   |
|                    |                                                   | I <sub>C</sub> = −4 A; I <sub>B</sub> = −200 mA                              | -                     | −150  | −225  | mV   |
|                    |                                                   | I <sub>C</sub> = −4 A; I <sub>B</sub> = −40 mA                               | -                     | −250  | −375  | mV   |
|                    | I <sub>C</sub> = −6.5 A; I <sub>B</sub> = −325 mA | -                                                                            | −235                  | −350  | mV    |      |
| R <sub>CEsat</sub> | collector-emitter saturation resistance           | I <sub>C</sub> = −5 A; I <sub>B</sub> = −500 mA                              | <a href="#">[1]</a> - | 36    | 54    | mΩ   |
| V <sub>BEsat</sub> | base-emitter saturation voltage                   | <a href="#">[1]</a>                                                          |                       |       |       |      |
|                    |                                                   | I <sub>C</sub> = −1 A; I <sub>B</sub> = −100 mA                              | -                     | −0.85 | −1    | V    |
|                    |                                                   | I <sub>C</sub> = −4 A; I <sub>B</sub> = −400 mA                              | -                     | −1    | −1.2  | V    |
| V <sub>BEon</sub>  | base-emitter turn-on voltage                      | V <sub>CE</sub> = −2 V; I <sub>C</sub> = −2 A                                | <a href="#">[1]</a> - | −0.76 | −0.85 | V    |
| t <sub>d</sub>     | delay time                                        | V <sub>CC</sub> = −12.5 V; I <sub>C</sub> = −1 A;                            | -                     | 40    | -     | ns   |
| t <sub>r</sub>     | rise time                                         | I <sub>Bon</sub> = −0.05 A; I <sub>Boff</sub> = 0.05 A                       | -                     | 55    | -     | ns   |
| t <sub>on</sub>    | turn-on time                                      |                                                                              | -                     | 95    | -     | ns   |
| t <sub>s</sub>     | storage time                                      |                                                                              | -                     | 340   | -     | ns   |
| t <sub>f</sub>     | fall time                                         |                                                                              | -                     | 85    | -     | ns   |
| t <sub>off</sub>   | turn-off time                                     |                                                                              | -                     | 425   | -     | ns   |
| f <sub>T</sub>     | transition frequency                              | V <sub>CE</sub> = −10 V; I <sub>C</sub> = −100 mA;<br>f = 100 MHz            | -                     | 105   | -     | MHz  |
| C <sub>c</sub>     | collector capacitance                             | V <sub>CB</sub> = −10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A;<br>f = 1 MHz | -                     | 95    | -     | pF   |

[1] Pulse test:  $t_p \leq 300\text{ }\mu\text{s}$ ;  $\delta \leq 0.02$ .



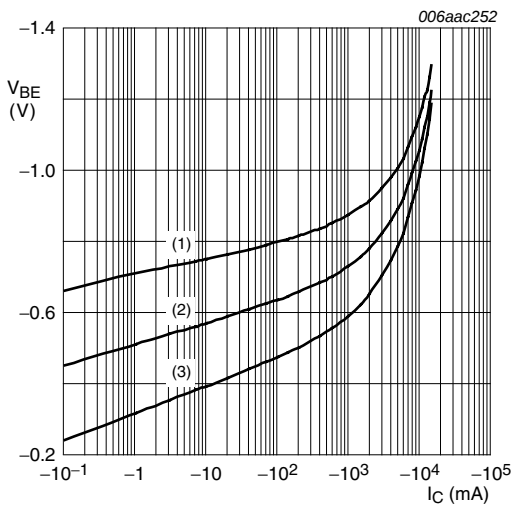
- $V_{CE} = -2\text{ V}$
- (1)  $T_{amb} = 100\text{ }^{\circ}\text{C}$
  - (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$
  - (3)  $T_{amb} = -55\text{ }^{\circ}\text{C}$

Fig 5. DC current gain as a function of collector current; typical values



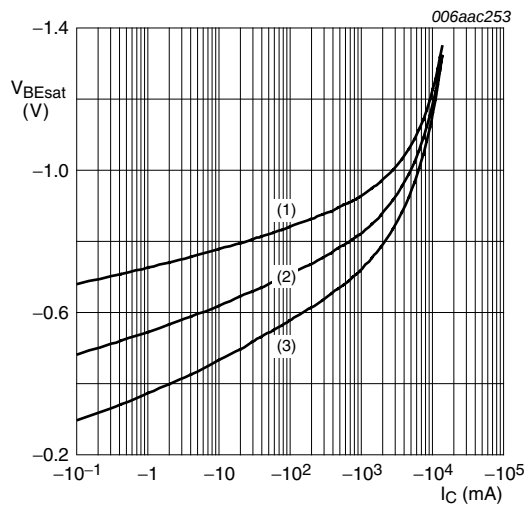
$T_{amb} = 25\text{ }^{\circ}\text{C}$

Fig 6. Collector current as a function of collector-emitter voltage; typical values



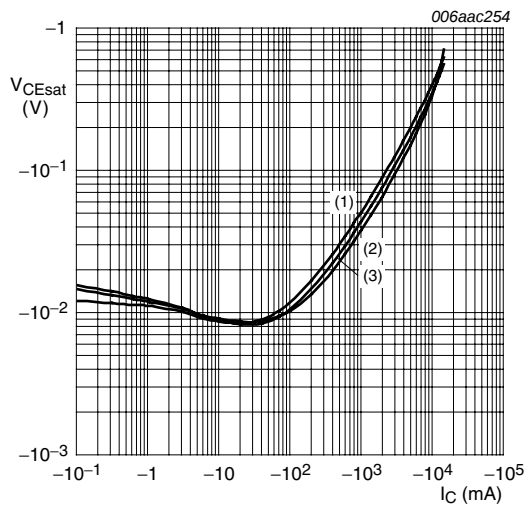
- $V_{CE} = -2\text{ V}$
- (1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$
  - (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$
  - (3)  $T_{amb} = 100\text{ }^{\circ}\text{C}$

Fig 7. Base-emitter voltage as a function of collector current; typical values



- $I_C/I_B = 20$
- (1)  $T_{amb} = -55\text{ }^{\circ}\text{C}$
  - (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$
  - (3)  $T_{amb} = 100\text{ }^{\circ}\text{C}$

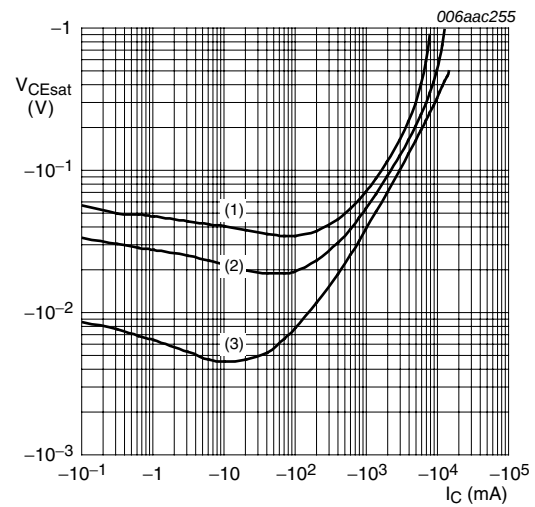
Fig 8. Base-emitter saturation voltage as a function of collector current; typical values



$$I_C/I_B = 20$$

- (1)  $T_{amb} = 100\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = -55\text{ °C}$

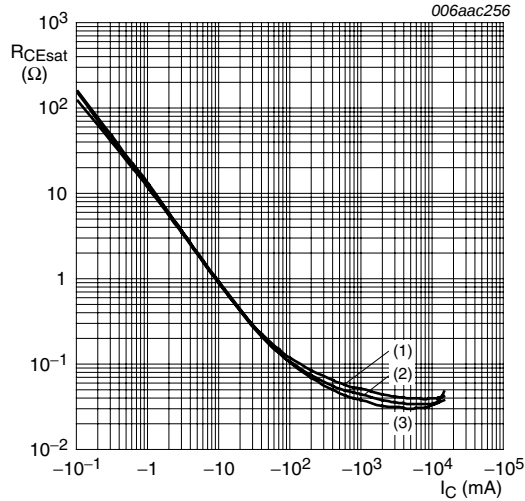
**Fig 9. Collector-emitter saturation voltage as a function of collector current; typical values**



$$T_{amb} = 25\text{ °C}$$

- (1)  $I_C/I_B = 100$
- (2)  $I_C/I_B = 50$
- (3)  $I_C/I_B = 10$

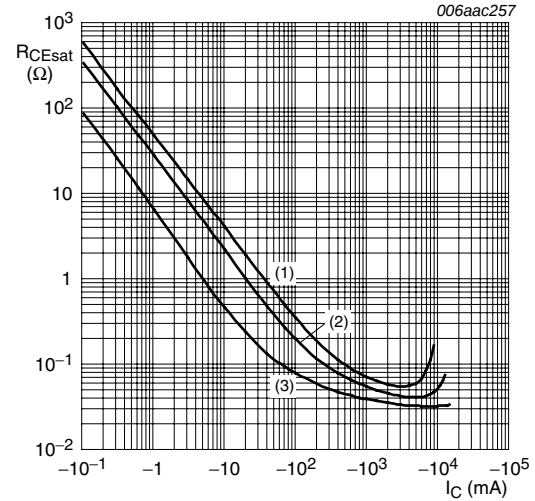
**Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values**



$$I_C/I_B = 20$$

- (1)  $T_{amb} = 100\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = -55\text{ °C}$

**Fig 11. Collector-emitter saturation resistance as a function of collector current; typical values**



$$T_{amb} = 25\text{ °C}$$

- (1)  $I_C/I_B = 100$
- (2)  $I_C/I_B = 50$
- (3)  $I_C/I_B = 10$

**Fig 12. Collector-emitter saturation resistance as a function of collector current; typical values**

8. Test information

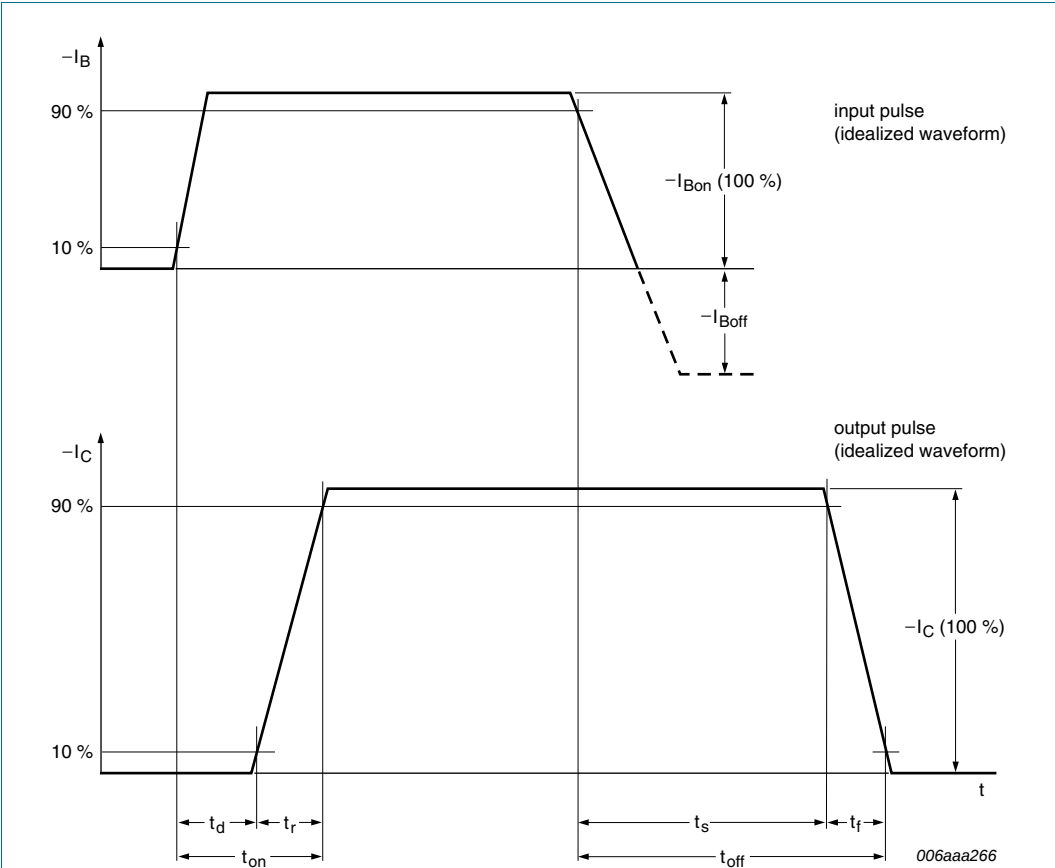


Fig 13. BISS transistor switching time definition

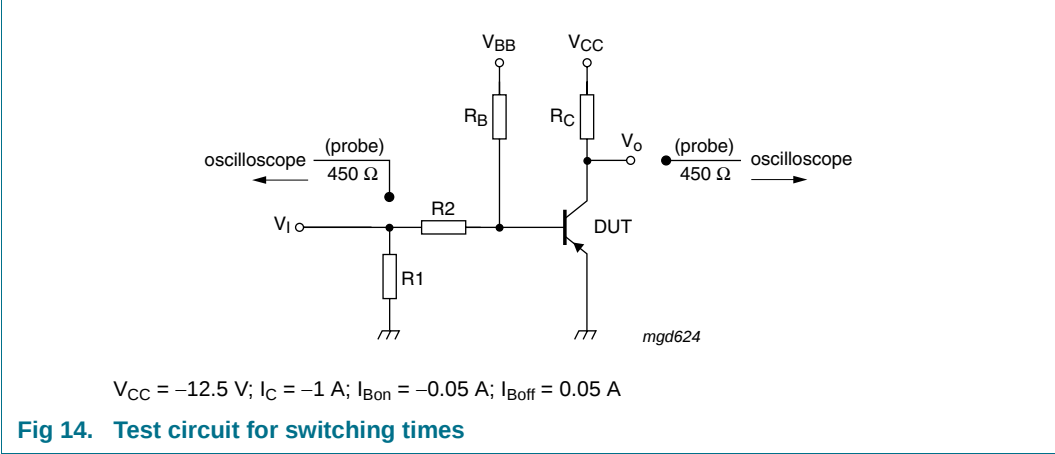
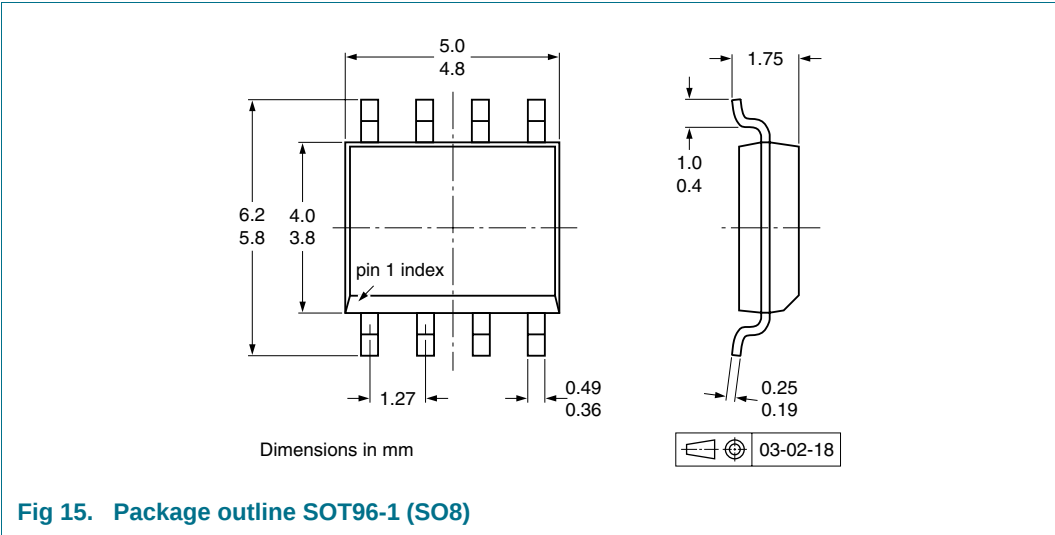


Fig 14. Test circuit for switching times

9. Package outline



10. Packing information

**Table 9. Packing methods**  
The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

| Type number | Package | Description                     | Packing quantity |      |
|-------------|---------|---------------------------------|------------------|------|
|             |         |                                 | 1000             | 2500 |
| PBSS4021SP  | SOT96-1 | 8 mm pitch, 12 mm tape and reel | -115             | -118 |

[1] For further information and the availability of packing methods, see [Section 14](#).

11. Soldering

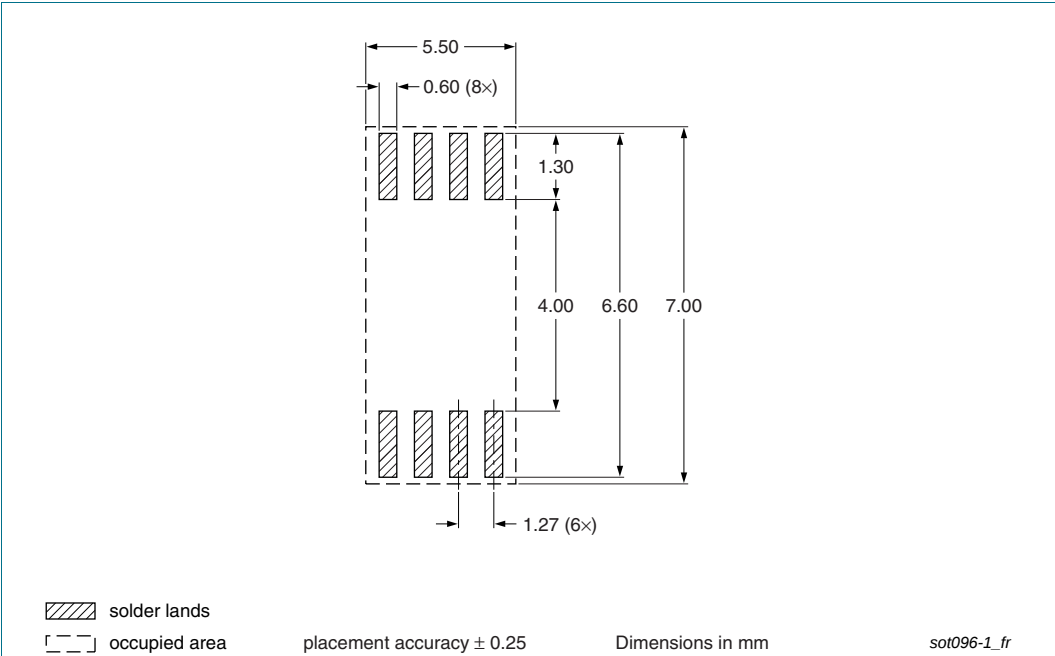


Fig 16. Reflow soldering footprint SOT96-1 (SO8)

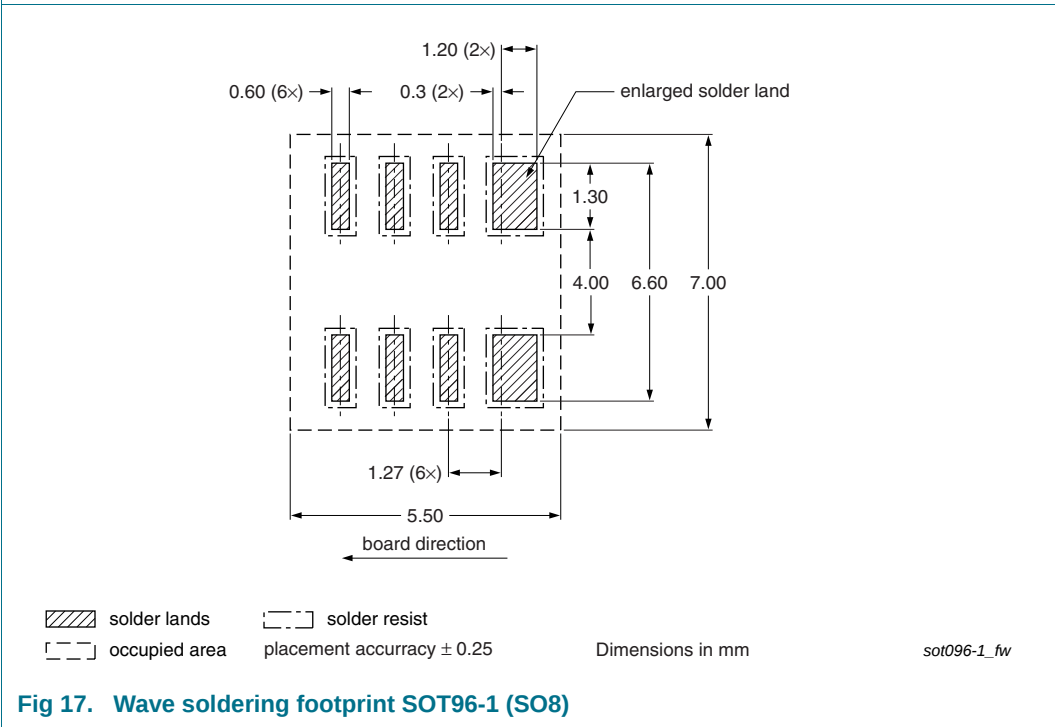


Fig 17. Wave soldering footprint SOT96-1 (SO8)

12. Revision history

Table 10. Revision history

| Document ID    | Release date                                                              | Data sheet status  | Change notice | Supersedes     |
|----------------|---------------------------------------------------------------------------|--------------------|---------------|----------------|
| PBSS4021SP v.2 | 20101011                                                                  | Product data sheet | -             | PBSS4021SP v.1 |
| Modifications: | • <a href="#">Figure 1 “Per device: Power derating curves”</a> : updated. |                    |               |                |
| PBSS4021SP v.1 | 20100714                                                                  | Product data sheet | -             | -              |

## 13. Legal information

### 13.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

## 13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 14. Contact information

For more information, please visit: <http://www.nexperia.com>

For sales office addresses, please send an email to: [salesaddresses@nexperia.com](mailto:salesaddresses@nexperia.com)

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## Данный компонент на территории Российской Федерации

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<http://moschip.ru/get-element>

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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